NSN 5961-01-569-3427

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Semiconductor Material:
Silicon
Special Features:
The high power radar transistor device is designed for I-band radar systems operating over the instantaneous bandwidth of 1.210-1.400 ghz
while operating in class c mode this common base device supplies a of 370 watts of peak pulse power
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig: